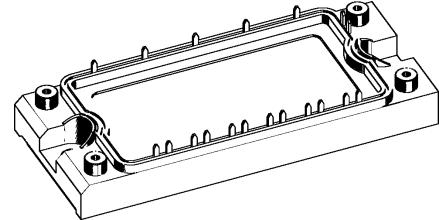
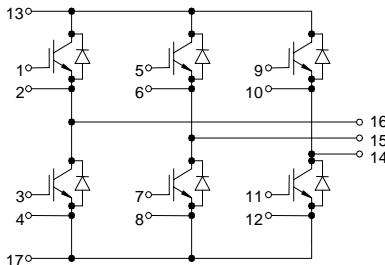


IGBT Module

Sixpack

Short Circuit SOA Capability
Square RBSOA

I_{C25} = 90 A
 V_{CES} = 1200 V
 $V_{CE(sat)\text{ typ.}}$ = 1.9 V



IGBTs

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	1200		V
V_{GES}		± 20		V
I_{C25}	$T_C = 25^\circ\text{C}$	90		A
I_{C80}	$T_C = 80^\circ\text{C}$	62		A
I_{CM}	$V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$; $T_{VJ} = 125^\circ\text{C}$	100		A
V_{CEK}	RBSOA; clamped inductive load; $L = 100 \mu\text{H}$	V_{CES}		
t_{sc}	$V_{CE} = 900 \text{ V}$; $V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$; $T_{VJ} = 125^\circ\text{C}$ SCSOA; non-repetitive	10	μs	
P_{tot}	$T_C = 25^\circ\text{C}$	350		W

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
$V_{CE(sat)}$	$I_C = 50 \text{ A}$; $V_{GE} = 15 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	1.9 2.1	2.4 2.1	V
$V_{GE(th)}$	$I_C = 2 \text{ mA}$; $V_{GE} = V_{CE}$	4.5	6.5	V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	0.8	0.8	mA
I_{GES}	$V_{CE} = 0 \text{ V}$; $V_{GE} = \pm 20 \text{ V}$		200	nA
$t_{d(on)}$ t_s $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 600 \text{ V}$; $I_C = 50 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$	150 60 680 50 6.0 5.0		ns ns ns ns mJ mJ
C_{ies}		3.8		nF
Q_{Gon}		500		nC
R_{thJC}			0.35	K/W

IXYS reserves the right to change limits, test conditions and dimensions.

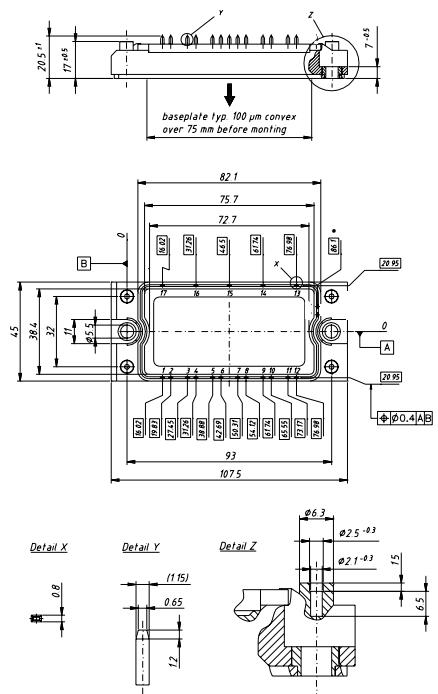
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Diodes

Symbol	Conditions	Maximum Ratings		
I _{F25}	T _C = 25°C	110	A	
I _{F80}	T _C = 80°C	70	A	

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V _F	I _F = 50 A; V _{GE} = 0 V; T _{VJ} = 25°C T _{VJ} = 125°C	2.2	2.6	V
		1.6		V
I _{RM} t _{rr}	I _F = 60 A; di _F /dt = -500 A/μs; T _{VJ} = 125°C V _R = 600 V; V _{GE} = 0 V	40		A
		200		ns
R _{thJC}	(per diode)		0.61	K/W

Dimensions in mm (1 mm = 0.0394")



Module

Symbol	Conditions	Maximum Ratings		
T _{VJ}		-40...+150	°C	
T _{stg}		-40...+125	°C	
V _{ISOL}	I _{ISOL} ≤ 1 mA; 50/60 Hz	2500	V~	
M _d	Mounting torque (M5)	2.7 - 3.3	Nm	

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R _{pin-chip}		5		mΩ
d _s	Creepage distance on surface	6		mm
d _A	Strike distance in air	6		mm
R _{thCH}	with heatsink compound	0.02		K/W
Weight		180		g